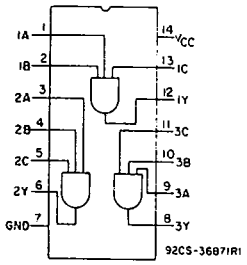
T-43-21-00

CD54/74HC11
CD54/74HCT11

File Number 1475

HARRIS SEMICOND SECTOR 27E D 4302271 0017479 2 HAS

High-Speed CMOS Logic



FUNCTIONAL DIAGRAM AND TERMINAL ASSIGNMENT

Triple 3-Input AND Gate

Type Features:

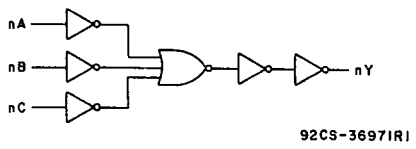
- *Buffered inputs*
- *Typical propagation delay = 8 ns @ V_{CC} = 5 V, C_L = 15 pF, T_A = 25° C*

The RCA-CD54/74HC11 and CD54/74HCT11 logic gates utilize silicon-gate CMOS technology to achieve operating speeds similar to LSTTL gates with the low power consumption of standard CMOS integrated circuits. All devices have the ability to drive 10 LSTTL loads. The 54HCT/74HCT logic family is functionally as well as pin compatible with the standard 54LS/74LS logic family.

The CD54HC11 and CD54HCT11 are supplied in 14-lead hermetic dual-in-line ceramic packages (F suffix). The CD74HC11 and CD74HCT11 are supplied in 14-lead dual-in-line plastic packages (E suffix) and in 14-lead dual-in-line surface mount plastic packages (M suffix). Both types are also available in chip form (H suffix).

Family Features:

- *Fanout [Over Temperature Range]:*
  Standard Outputs - 10 LSTTL Loads
  Bus Driver Outputs - 15 LSTTL Loads
- *Wide Operating Temperature Range:*
  CD74HC/HCT: -40 to +85° C
- *Balanced Propagation Delay and Transition Times*
- *Significant Power Reduction Compared to LSTTL Logic ICs*
- *Alternate Source is Phillips/Signetics*
- *CD54HC/CD74HC Types:*
  2 to 6 V Operation
  High Noise Immunity: N_{IL}=30%, N_{IH}=30% of V_{CC} @ V_{CC}=5 V
- *CD54HCT/CD74HCT Types:*
  4.5 to 5.5 V Operation
  Direct LSTTL Input Logic Compatibility
  V_{IL}=0.8 V Max., V_{IH}=2 V Min.
  CMOS Input Compatibility
  $I_I \leq 1\ \mu A$ @ V_{OL}, V_{OH}



LOGIC DIAGRAM

TRUTH TABLE

INPUTS			OUTPUTS
nA	nB	nC	nY
L	L	L	L
L	L	H	L
L	H	L	L
L	H	H	L
H	L	L	L
H	L	H	L
H	H	L	L
H	H	H	H

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MAXIMUM RATINGS, *Absolute-Maximum Values:*

DC SUPPLY-VOLTAGE, (V_{CC}):
(Voltages referenced to ground) ..... -0.5 to +7 V
DC INPUT DIODE CURRENT, I_{IK} (FOR $V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ..... ±20 mA
DC OUTPUT CURRENT, I_{OK} (FOR $V_o < -0.5V$ OR $V_o > V_{CC} + 0.5V$) ..... ±20 mA
DC DRAIN CURRENT, PER OUTPUT (I_o) (FOR $-0.5V < V_o < V_{CC} + 0.5V$) ..... ±25 mA
DC V_{CC} OR GROUND CURRENT, (I_{CC}): ..... ±50 mA
POWER DISSIPATION PER PACKAGE (P_D):
For T_A = -40 to +60°C (PACKAGE TYPE E) ..... 500 mW
For T_A = +60 to+85°C (PACKAGE TYPE E) ..... Derate Linearly at 8 mW/°C to 300 mW
For T_A = -55 to +100°C (PACKAGE TYPE F, H) ..... 500 mW
For T_A = +100 to +125°C (PACKAGE TYPE F, H) ..... Derate Linearly at 8 mW/°C to 300 mW
For T_A = -40 to +70°C (PACKAGE TYPE M) ..... 400 mW
For T_A = +70 to +125°C (PACKAGE TYPE M) ..... Derate Linearly at 6 mW/°C to 70 mW
OPERATING-TEMPERATURE RANGE (T_A):
PACKAGE TYPE F, H ..... -55 to +125°C
PACKAGE TYPE E, M ..... -40 to +85°C
STORAGE TEMPERATURE (T_{stg}) ..... -65 to +150°C
LEAD TEMPERATURE (DURING SOLDERING):
At distance 1/16 ± 1/32 in. (1.59 ± 0.79 mm) from case for 10 s max. ..... +265°C
Unit inserted into a PC Board (min. thickness 1/16 in., 1.59 mm)
with solder contacting lead tips only ..... +300°C

RECOMMENDED OPERATING CONDITIONS:
For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges:

CHARACTERISTIC	LIMITS		UNITS
	MIN.	MAX.	
Supply-Voltage Range (For T_A = Full Package Temperature Range) V_{CC}:*			
CD54/74HC Types	2	6	V
CD54/74HCT Types	4.5	5.5	V
DC Input or Output Voltage V_{in}, V_{out}	0	V_{CC}	V
Operating Temperature T_A:			
CD74 Types	-40	+85	°C
CD54 Types	-55	+125	°C
Input Rise and Fall Times t_r, t_f			
at 2 V	0	1000	ns
at 4.5 V	0	500	ns
at 6 V	0	400	ns

*Unless otherwise specified, all voltages are referenced to Ground.

CD54/74HC11
CD54/74HCT11

HARRIS SEMICOND SECTOR 27E D 4302271 0017481 0 HAS

STATIC ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	CD74HC11/CD54HC11										CD74HCT11/CD54HCT11									UNITS
	TEST CONDITIONS			74HC/54HC TYPES			74HC TYPES		54HC TYPES		TEST CONDITIONS		74HCT/54HCT TYPES			74HCT TYPES		54HCT TYPES		
	V_I V	I_O mA	V_{CC} V	+25°C			-40/ +85°C		-55/ +125°C		V_I V	V_{CC} V	+25°C			-40/ +85°C		-55/ +125°C		
				Min	Typ	Max	Min	Max	Min	Max			Min	Typ	Max	Min	Max	Min	Max	
High-Level Input Voltage V_{IH}			2	1.5	—	—	1.5	—	1.5	—	—	4.5 to 5.5	2	—	—	2	—	2	—	V
			4.5	3.15	—	—	3.15	—	3.15	—										
			6	4.2	—	—	4.2	—	4.2	—										
Low-Level Input Voltage V_{IL}			2	—	—	0.5	—	0.5	—	0.5	—	4.5 to 5.5	—	—	0.8	—	0.8	—	0.8	V
			4.5	—	—	1.35	—	1.35	—	1.35										
			6	—	—	1.8	—	1.8	—	1.8										
High-Level Output Voltage V_{OH} CMOS Loads	V_{IL} or V_{IH}	-0.02	2	1.9	—	—	1.9	—	1.9	—	V_{IL} or V_{IH}	4.5	4.4	—	—	4.4	—	4.4	—	V
			4.5	4.4	—	—	4.4	—	4.4	—										
			6	5.9	—	—	5.9	—	5.9	—										
TTL Loads	V_{IL} or V_{IH}	-4	4.5	3.98	—	—	3.84	—	3.7	—	V_{IL} or V_{IH}	4.5	3.98	—	—	3.84	—	3.7	—	V
		-5.2	6	5.48	—	—	5.34	—	5.2	—										
Low-Level Output Voltage V_{OL} CMOS Loads	V_{IL} or V_{IH}	0.02	2	—	—	0.1	—	0.1	—	0.1	V_{IL} or V_{IH}	4.5	—	—	0.1	—	0.1	—	0.1	V
			4.5	—	—	0.1	—	0.1	—	0.1										
			6	—	—	0.1	—	0.1	—	0.1										
TTL Loads	V_{IL} or V_{IH}	4	4.5	—	—	0.26	—	0.33	—	0.4	V_{IL} or V_{IH}	4.5	—	—	0.26	—	0.33	—	0.4	V
		5.2	6	—	—	0.26	—	0.33	—	0.4										
Input Leakage Current I_I	V_{CC} or Gnd		6	—	—	±0.1	—	±1	—	±1	Any Voltage Between V_{CC} & Gnd	5.5	—	—	±0.1	—	±1	—	±1	µA
Quiescent Device Current I_{CC}	V_{CC} or Gnd	0	6	—	—	2	—	20	—	40	V_{CC} or & Gnd	5.5	—	—	2	—	20	—	40	µA
Additional Quiescent Device Current per input pin, 1 unit load ΔI_{CC}*											V_{CC}-2.1	4.5 to 5.5	—	100	360	—	450	—	490	µA

*For dual-supply systems theoretical worst case (V_I = 2.4 V, V_{CC} = 5.5 V) specification is 1.8 mA.

HCT Input Loading Table

Input	Unit Loads*
ALL	0.50

*Unit Load is ΔI_{CC} limit specified in Static Characteristic Chart, e.g., 360 µA max. @ 25°C.

CD54/74HC11
CD54/74HCT11

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SWITCHING CHARACTERISTICS (C_L = 50 pF, Input t_r, t_f = 6 ns)

CHARACTERISTIC	SYMBOL	V_{CC}	25°C				-40°C to +85°C				-55°C to +125°C				UNITS
			HC		HCT		74HC		74HCT		54HC		54HCT		
			Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
Propagation Delay, Input to Output (Fig. 1)	t_{PLH}	2	—	100	—	—	—	125	—	—	—	150	—	—	ns
	t_{PHL}	4.5	—	20	—	28	—	25	—	35	—	30	—	42	
		6	—	17	—	—	—	21	—	—	—	26	—	—	
Transition Times (Fig. 1)	t_{TLH}	2	—	75	—	—	—	95	—	—	—	110	—	—	ns
	t_{THL}	4.5	—	15	—	15	—	19	—	19	—	22	—	22	
		6	—	13	—	—	—	16	—	—	—	19	—	—	
Input Capacitance	C_I		—	10	—	10	—	10	—	— 10 —	—	10 -	—	10	pF

SWITCHING CHARACTERISTICS (V_{CC} = 5 V, T_A = 25°C, Input t_r, t_f = 6 ns)

CHARACTERISTIC	SYMBOL	Typical		Units
		HC	HCT	
Propagation Delay, Data Input to Output Y (Fig. 1) (C_L = 15 pF)	t_{PLH} t_{PHL}	8	11	ns
Power Dissipation Capacitance*	C_{PD}	26	28	pF

*C_{PD} is used to determine the dynamic power consumption, per gate.
$P_D = V_{CC}^2 f_i (C_{PD} + C_L)$ where f_i = input frequency
C_L = output load capacitance
V_{CC} = supply voltage

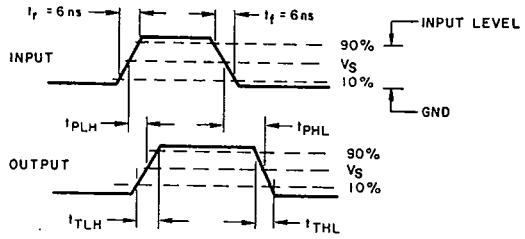

Fig. 1 — Transition times and propagation delay times.

	54/74HC	54/74HCT
INPUT LEVEL	V_{CC}	3V
V_S	50% V_{CC}	1.3V